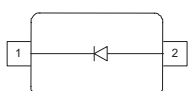


Silicon PIN Diodes

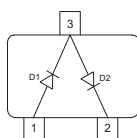
- PIN diode for high speed switching of RF signals
- Very low forward resistance (low insertion loss)
- Very low capacitance (high isolation)
- For frequencies up to 3GHz
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101¹⁾



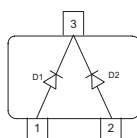
BAR63-02..
BAR63-03W



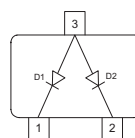
BAR63-04
BAR63-04W



BAR63-05
BAR63-05W



BAR63-06
BAR63-06W



Type	Package	Configuration	L_s (nH)	Marking
BAR63-02L*	TSLP-2-1	single, leadless	0.4	G
BAR63-02V	SC79	single	0.6	G
BAR63-02W	SCD80	single	0.6	GG
BAR63-03W	SOD323	single	1.8	white G
BAR63-04	SOT23	series	1.8	G4s
BAR63-04W	SOT323	series	1.4	G4s
BAR63-05	SOT23	common cathode	1.8	G5s
BAR63-05W	SOT323	common cathode	1.4	G5s
BAR63-06	SOT23	common anode	1.8	G6s
BAR63-06W	SOT323	common anode	1.4	G6s

¹*BAR63-02L is not qualified according AEC Q101

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	50	V
Forward current	I_F	100	mA
Total power dissipation BAR63-02L, $T_S \leq 118^\circ\text{C}$ BAR63-02V, -02W, BAR63-03W, $T_S \leq 115^\circ\text{C}$ BAR63-04...BAR63-06, $T_S \leq 55^\circ\text{C}$ BAR63-04S, $T_S \leq 115^\circ\text{C}$ BAR63-04W...BAR63-06W, $T_S \leq 105^\circ\text{C}$	P_{tot}	250 250 250 250 250	mW
Junction temperature	T_j	150	$^\circ\text{C}$
Operating temperature range	T_{op}	-55 ... 125	
Storage temperature	T_{stg}	-55 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾ BAR63-02L BAR63-02V, BAR63-02W BAR63-03W BAR63-04...BAR63-06 BAR63-04S BAR63-04W...BAR63-06W	R_{thJS}	≤ 125 ≤ 140 ≤ 155 ≤ 380 ≤ 180 ≤ 180	K/W

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

DC Characteristics

Breakdown voltage $I_{(\text{BR})} = 5 \mu\text{A}$	$V_{(\text{BR})}$	50	-	-	V
Reverse current $V_R = 35 \text{ V}$	I_R	-	-	10	nA
Forward voltage $I_F = 100 \text{ mA}$	V_F	-	0.95	1.2	V

¹⁾For calculation of R_{thJA} please refer to the Technical Information

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit	
		min.	typ.	max.		
AC Characteristics						
Diode capacitance $V_R = 5\text{ V}$, $f = 1\text{ MHz}$ $V_R = 0\text{ V}$, 100 MHz ... 1.8 GHz	C_T	- -	0.21 0.3	0.3 -	pF	
Reverse parallel resistance $V_R = 0\text{ V}$, $f = 100\text{ MHz}$ $V_R = 0\text{ V}$, $f = 1\text{ GHz}$ $V_R = 0\text{ V}$, $f = 1.8\text{ GHz}$	R_P	- - -	500 15 5	- - -	kΩ	
Forward resistance $I_F = 5\text{ mA}$, $f = 100\text{ MHz}$ $I_F = 10\text{ mA}$, $f = 100\text{ MHz}$	r_f	- -	1.2 1	2 -	Ω	
Charge carrier life time $I_F = 10\text{ mA}$, $I_R = 6\text{ mA}$, measured at $I_R = 3\text{ mA}$, $R_L = 100\text{ }\Omega$	τ_{rr}	-	75	-	ns	
I-region width	W_I	-	4.5	-	μm	
Insertion loss ¹⁾ $I_F = 1\text{ mA}$, $f = 1.8\text{ GHz}$ $I_F = 5\text{ mA}$, $f = 1.8\text{ GHz}$ $I_F = 10\text{ mA}$, $f = 1.8\text{ GHz}$	I_L	- - -	0.15 0.11 0.1	- - -	dB	
Isolation ¹⁾ $V_R = 0\text{ V}$, $f = 0.9\text{ GHz}$ $V_R = 0\text{ V}$, $f = 1.8\text{ GHz}$ $V_R = 0\text{ V}$, $f = 2.45\text{ GHz}$	I_{SO}	- - -	17.9 12.3 10	- - -		
Series inductance	L_S	-	-	-		

¹⁾BAR63-02L in series configuration, $Z = 50\Omega$

Diode capacitance $C_T = f(V_R)$

$f = 1\text{MHz} - 1.8\text{GHz}$



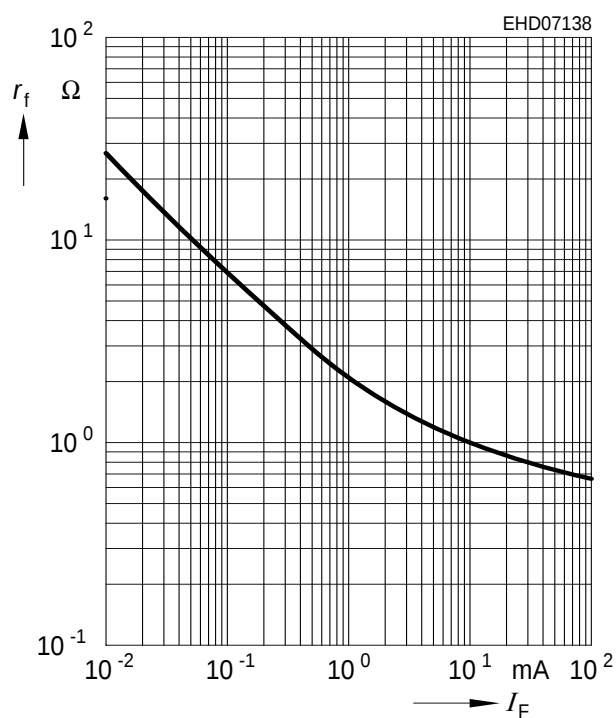
Reverse parallel resistance $R_P = f(V_R)$

$f = \text{Parameter}$



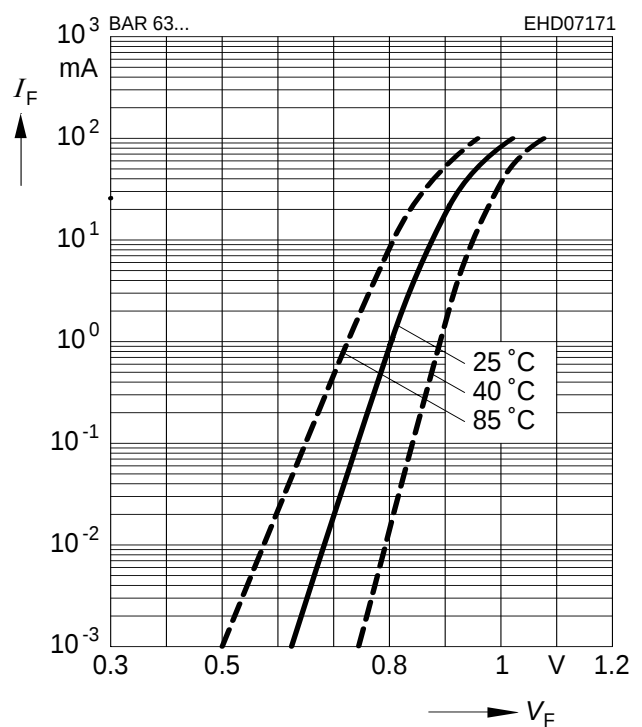
Forward resistance $r_f = f(I_F)$

$f = 100\text{MHz}$



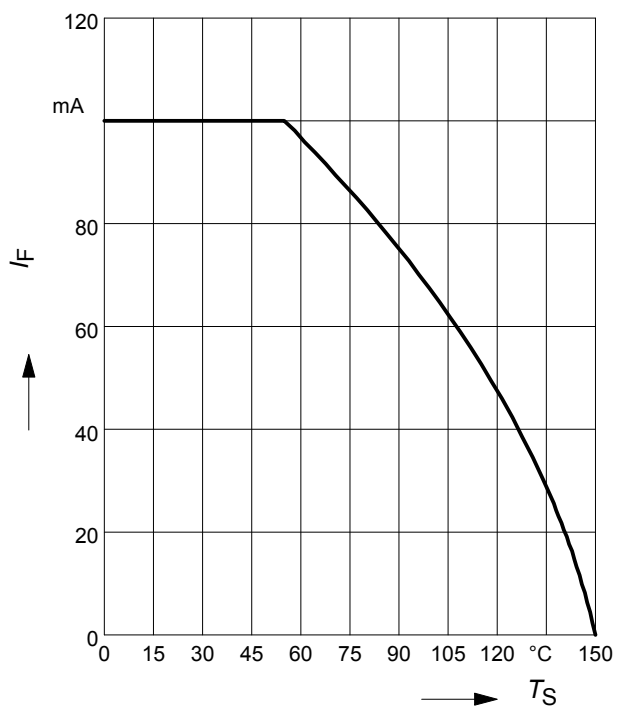
Forward current $I_F = f(V_F)$

$T_A = \text{Parameter}$



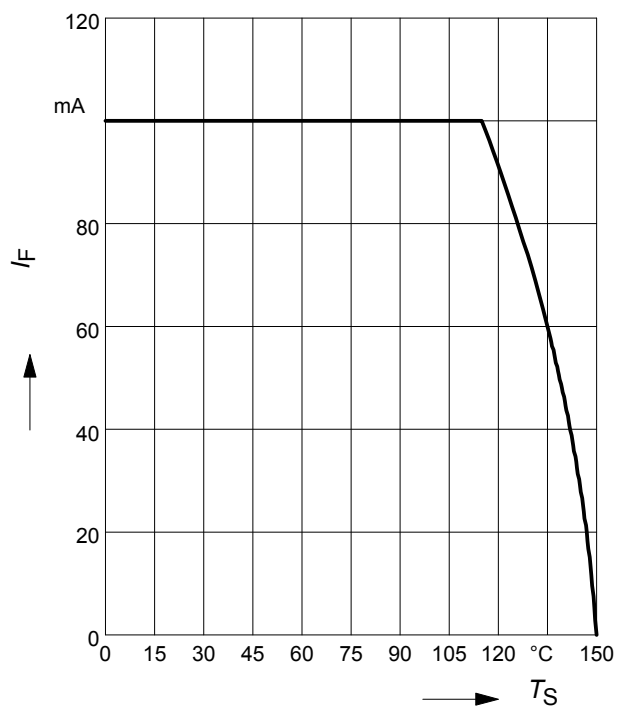
Forward current $I_F = f(T_S)$

BAR63-04...BAR63-06



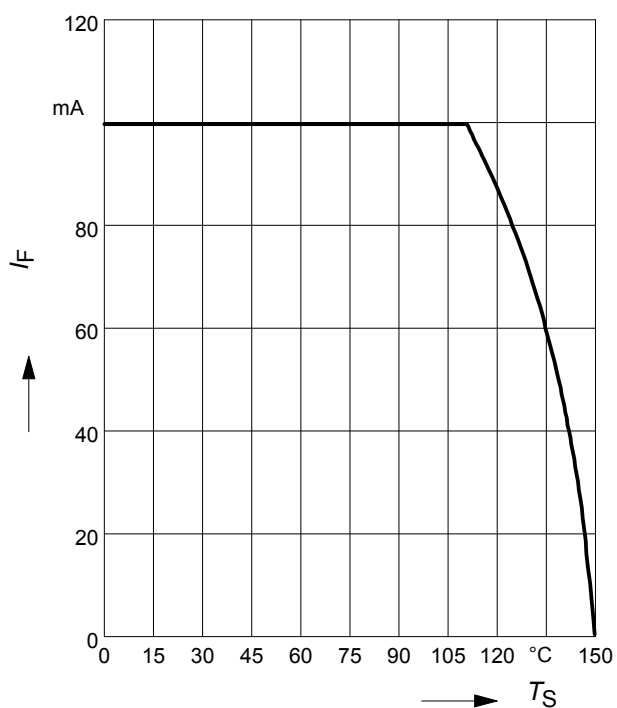
Forward current $I_F = f(T_S)$

BAR63-02V, BAR63-02W



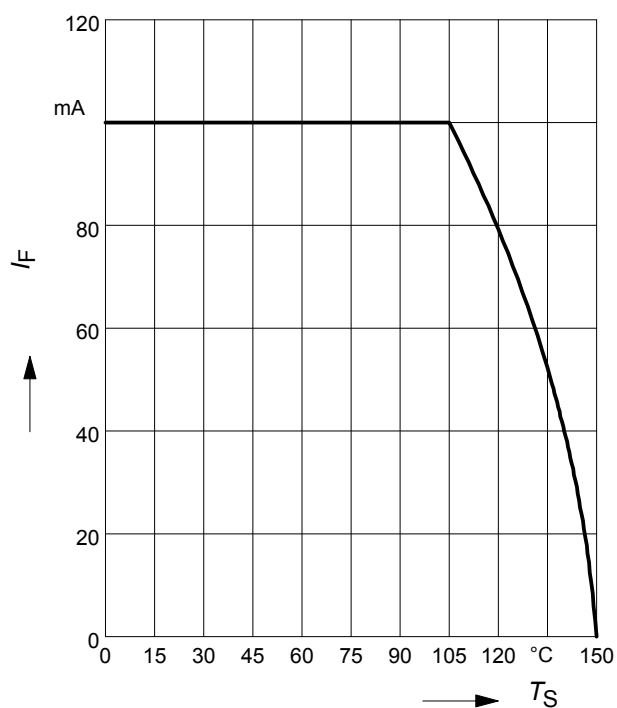
Forward current $I_F = f(T_S)$

BAR63-03W



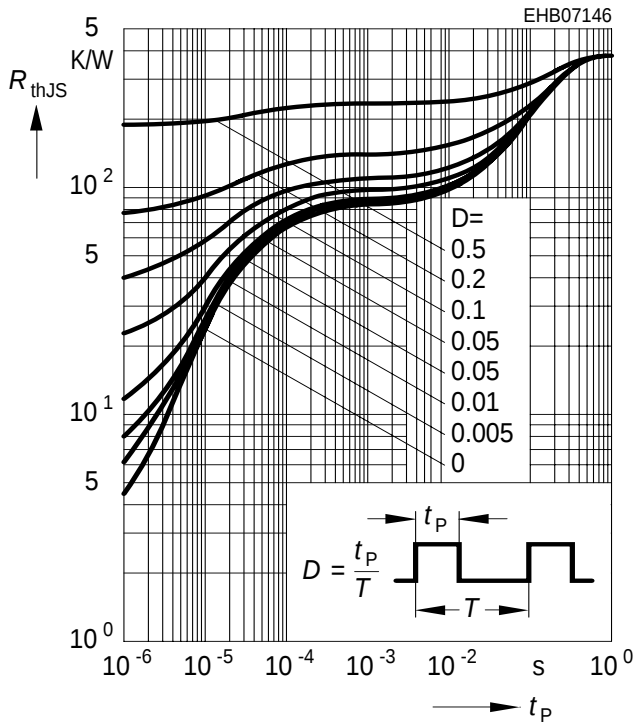
Forward current $I_F = f(T_S)$

BAR63-04W...BAR63-06W



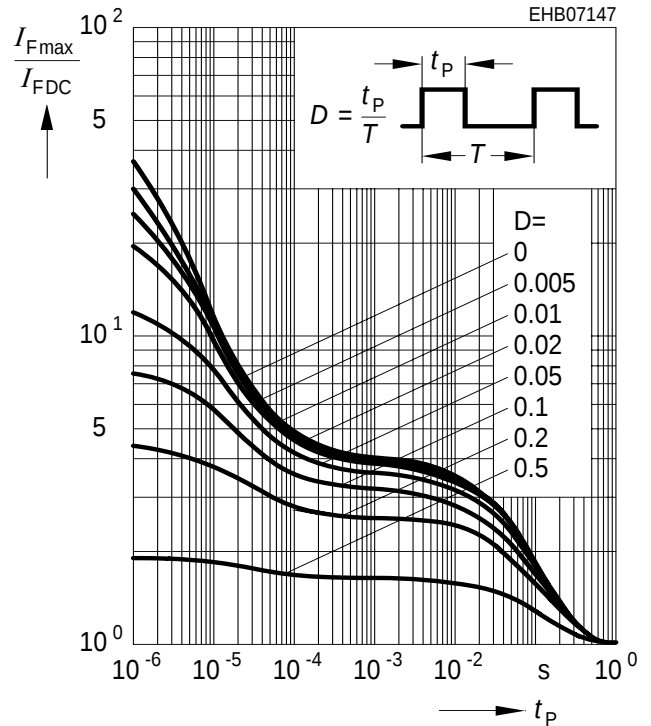
Permissible Puls Load $R_{thJS} = f(t_p)$

BAR63-04...BAR63-06

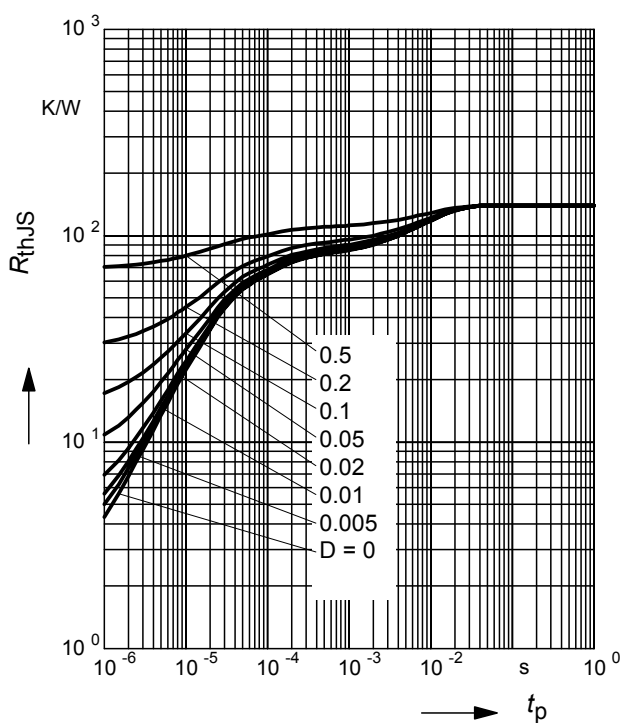

Permissible Pulse Load

$$I_{Fmax}/I_{FDC} = f(t_p)$$

BAR63-04...BAR63-06

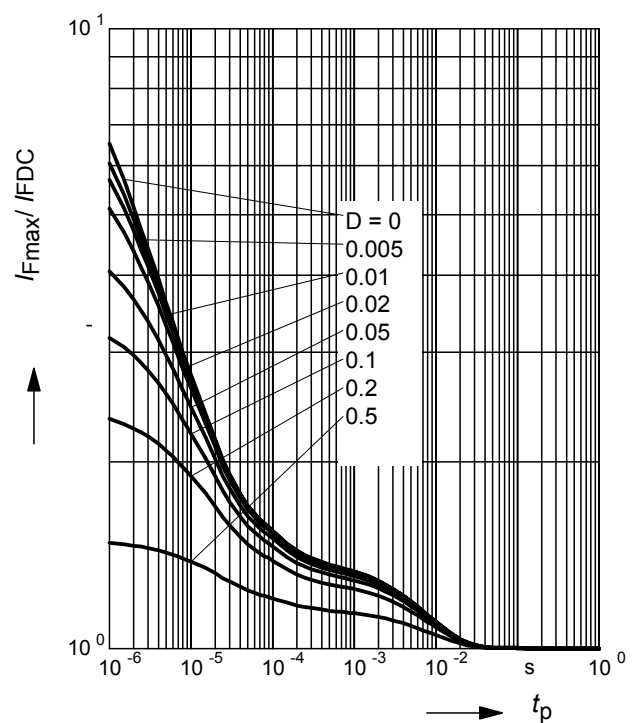

Permissible Puls Load $R_{thJS} = f(t_p)$

BAR63-02V, BAR63-02W


Permissible Pulse Load

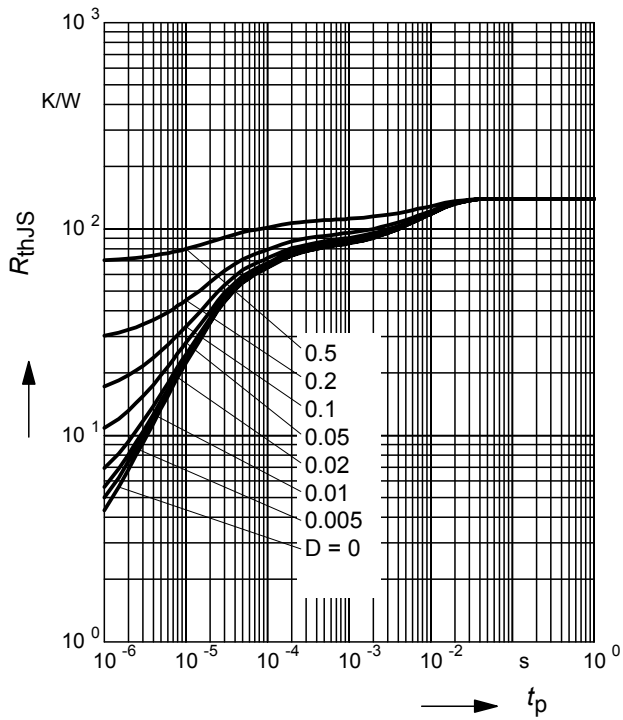
$$I_{Fmax}/I_{FDC} = f(t_p)$$

BAR63-02V, BAR63-02W



Permissible Puls Load $R_{thJS} = f(t_p)$

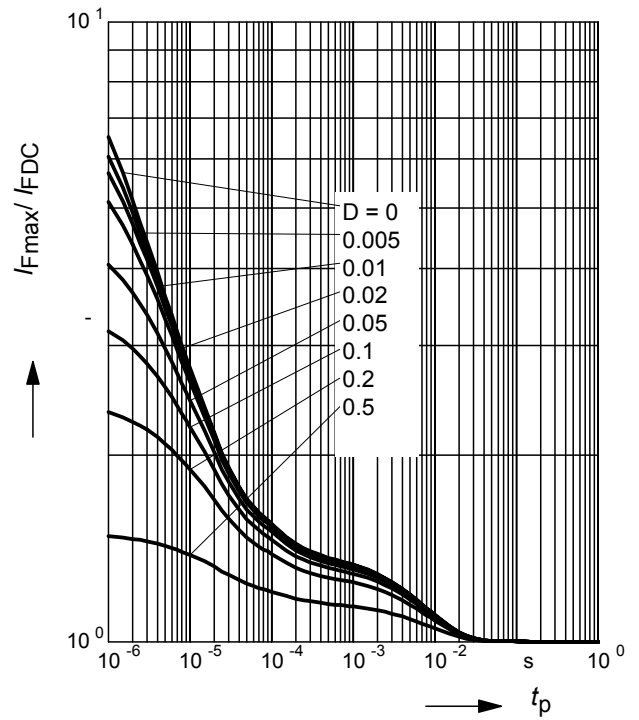
BAR63-03W



Permissible Pulse Load

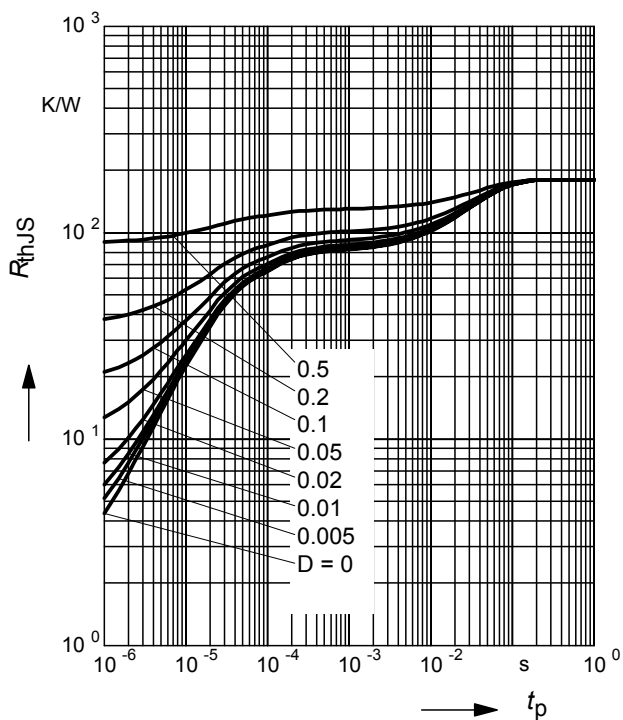
$$I_{Fmax}/I_{FDC} = f(t_p)$$

BAR63-03W



Permissible Puls Load $R_{thJS} = f(t_p)$

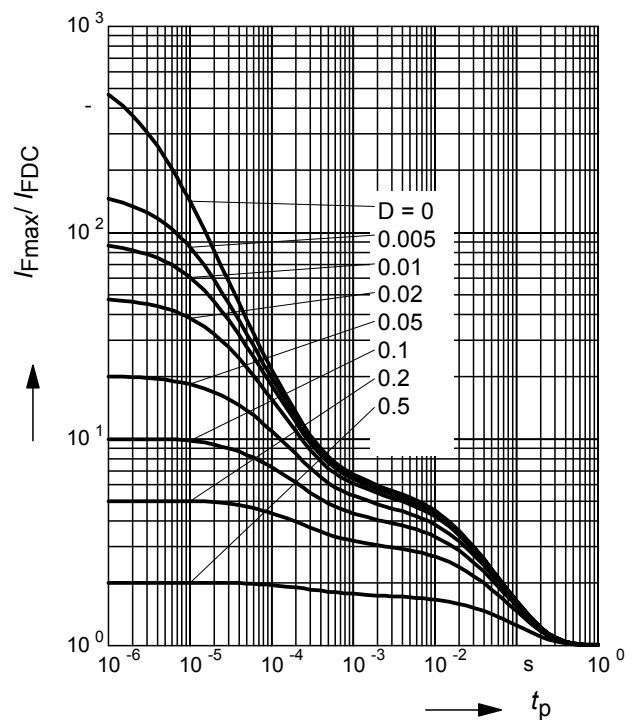
BAR63-04W...BAR63-06W



Permissible Pulse Load

$$I_{Fmax}/I_{FDC} = f(t_p)$$

BAR63-04W...BAR63-06W



Insertion loss $I_L = -|S_{21}|^2 = f(f)$

I_F = Parameter

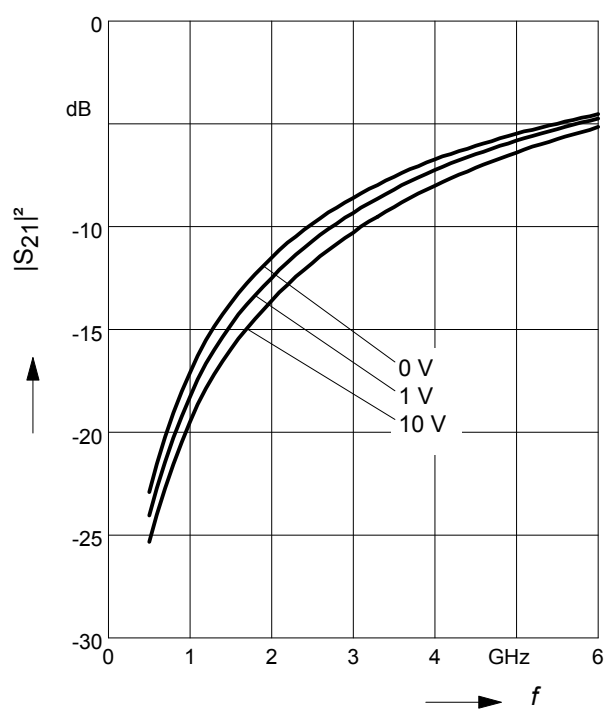
BAR63-02L in series configuration, $Z = 50\Omega$



Isolation $I_{SO} = -|S_{21}|^2 = f(f)$

V_R = Parameter

BAR63-02L in series configuration, $Z = 50\Omega$



The drawing shows the 100-01 package from two perspectives. The top view (left) is a square package with a central square pad labeled '2' and a cathode marking area labeled '1'. Dimensions include a total width of 0.8 ± 0.1 and a cathode marking width of 0.3 ± 0.05 . The side view (right) shows a package with a maximum height of 10°MAX. and a base width of 0.55 ± 0.04 . A detail view of the top surface shows a central pad with a diameter of $0.13^{+0.05}_{-0.03}$ and a total diameter of $0.2 \text{ } \textcircled{M} \text{ } \textcircled{A}$. The package is labeled '100-01'.

2005, June
Date code

BAR63-02V
Type code

Cathode marking
Laser marking

The image contains three technical drawings of cathode marking components. The first drawing, labeled 'Standard', shows a component with a width of 4, a height of 8, and a pitch of 1.33. It features two cathode markings, each with a diameter of 0.4 and a distance of 0.93 between them. The second drawing, labeled 'Reel with 2 mm Pitch', shows a component with a width of 2 and a pitch of 2. It also features two cathode markings, each with a diameter of 0.4 and a distance of 0.93 between them. The third drawing shows a side view of the component with a thickness of 0.2 and a distance of 0.66 between the cathode markings.

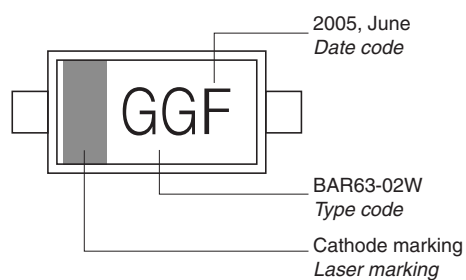
Package Outline



Foot Print



Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
 Reel ø180 mm = 8.000 Pieces/Reel (2 mm Pitch)
 Reel ø330 mm = 10.000 Pieces/Reel



Date Code marking for discrete packages with one digit (SCD80, SC79, SC75¹⁾) CES-Code

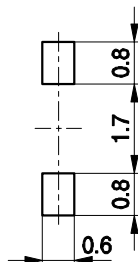
Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	a	p	A	P	a	p	A	P	a	p	A	P
02	b	q	B	Q	b	q	B	Q	b	q	B	Q
03	c	r	C	R	c	r	C	R	c	r	C	R
04	d	s	D	S	d	s	D	S	d	s	D	S
05	e	t	E	T	e	t	E	T	e	t	E	T
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	v	G	V	g	v	G	V	g	v	G	V
08	h	x	H	X	h	x	H	X	h	x	H	X
09	j	y	J	Y	j	y	J	Y	j	y	J	Y
10	k	z	K	Z	k	z	K	Z	k	z	K	Z
11	l	2	L	4	l	2	L	4	l	2	L	4
12	n	3	N	5	n	3	N	5	n	3	N	5

1) New Marking Layout for SC75, implemented at October 2005.

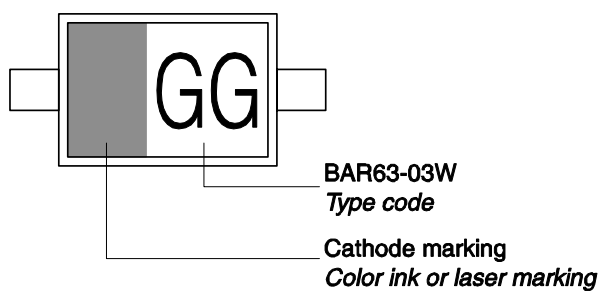
Package Outline



Foot Print

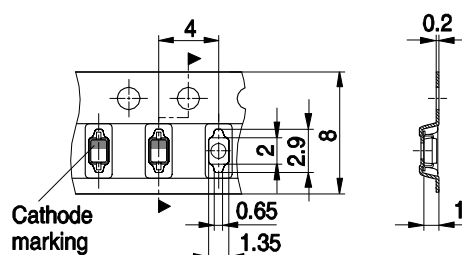


Marking Layout (Example)

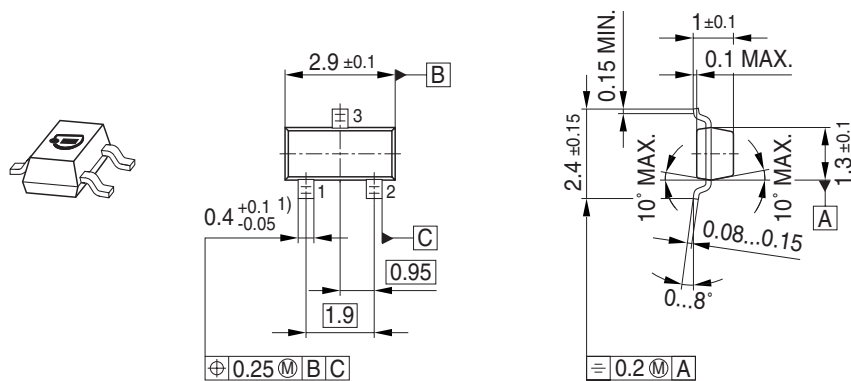


Standard Packing

Reel $\varnothing 180$ mm = 3.000 Pieces/Reel
 Reel $\varnothing 330$ mm = 10.000 Pieces/Reel

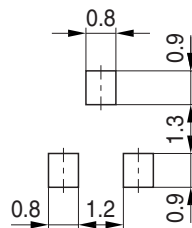


Package Outline

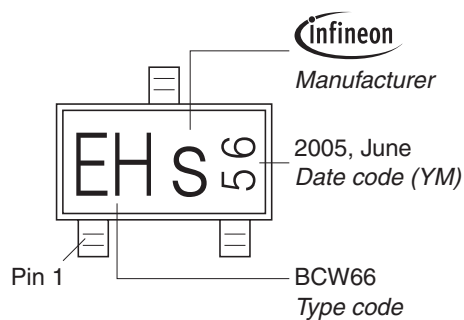


1) Lead width can be 0.6 max. in dambar area

Foot Print

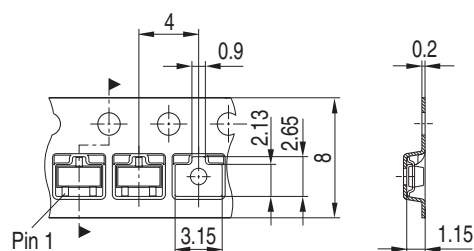


Marking Layout (Example)

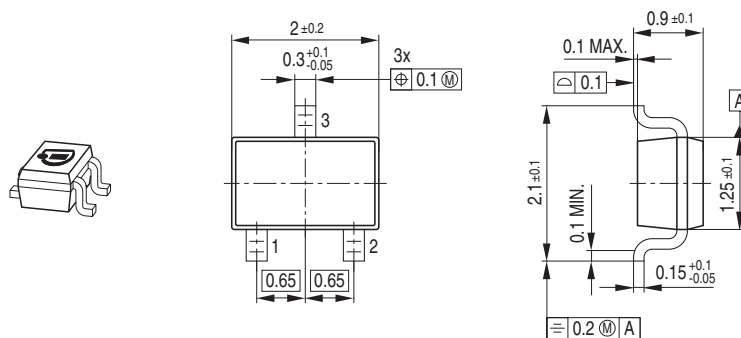


Standard Packing

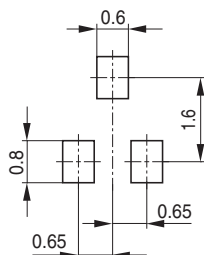
Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel



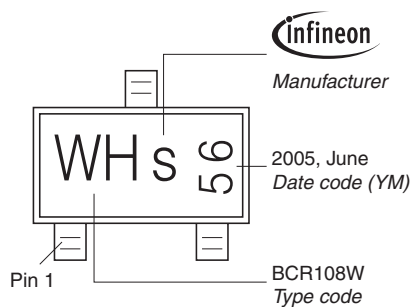
Package Outline



Foot Print

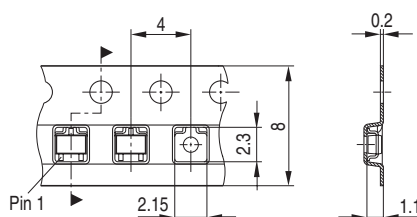


Marking Layout (Example)



Standard Packing

Reel $\varnothing 180$ mm = 3.000 Pieces/Reel
 Reel $\varnothing 330$ mm = 10.000 Pieces/Reel

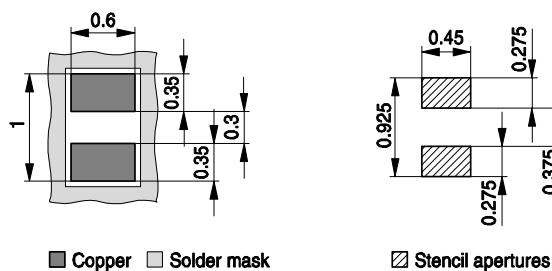


Package Outline

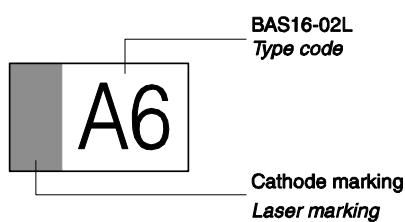


Foot Print

For board assembly information please refer to Infineon website "Packages"

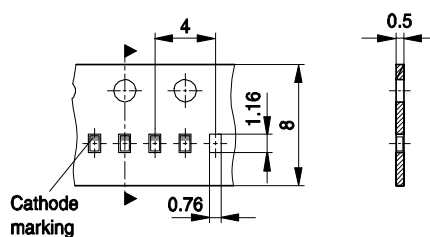


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel
Reel ø330 mm = 50.000 Pieces/Reel (optional)



Edition 2009-11-16

**Published by
Infineon Technologies AG
81726 Munich, Germany**

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